

LM4125 Precision Micropower Low Dropout Voltage Reference

Check for Samples: LM4125

FEATURES

- Small SOT23-5 Package
- Low Dropout Voltage: 120 mV Typ @ 1 mA
- High Output Voltage Accuracy: 0.2%
- Source and Sink Current Output: ±5 mA
- Supply Current: 160 μA Typ.
- Low Temperature Coefficient: 50 ppm/°C
- Fixed Output Voltages: 2.048, 2.5, and 4.096
- Industrial Temperature Range: -40°C to +85°C
- (For Extended Temperature Range, −40°C to 125°C, Contact TI)

APPLICATIONS

- Portable, Battery Powered Equipment
- Instrumentation and Process Control
- Automotive & Industrial
- Test Equipment
- Data Acquisition Systems
- · Precision Regulators
- Battery Chargers
- Base Stations
- Communications
- Medical Equipment

Connection Diagram

DESCRIPTION

The LM4125 is a precision low power low dropout bandgap voltage reference with up to 5 mA output current source and sink capability.

This series reference operates with input voltages as low as 2V and up to 6V consuming 160 μ A (Typ.) supply current. In power down mode, device current drops to less than 2 μ A.

The LM4125 comes in two grades (A and Standard) and three voltage options for greater flexibility. The best grade devices (A) have an initial accuracy of 0.2%, while the standard have an initial accuracy of 0.5%, both with a tempco of 50ppm/°C ensured from -40°C to +125°C.

The very low dropout voltage, low supply current and power-down capability of the LM4125 makes this product an ideal choice for battery powered and portable applications.

The device performance is ensured over the industrial temperature range (-40°C to +85°C), while certain specs are ensured over the extended temperature range (-40°C to +125°C). Please contact TI for full specifications over the extended temperature range. The LM4125 is available in a standard 5-pin SOT-23 package.

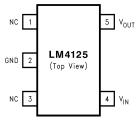


Figure 1. 5-Pin SOT-23 Surface Mount Package See Package Number DBV



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

M

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



Absolute Maximum Ratings (1)(2)

Maximum Voltage on input or enable pins		-0.3V to 8V		
Output Short-Circuit Duration		Indefinite		
Power Dissipation (T _A = 25°C) ⁽³⁾	DBV package - θ _{JA}	280°C/W		
	Power Dissipation	350 mW		
ESD Susceptibility ⁽⁴⁾	Human Body Model	2 kV		
	Machine Model	200V		
Lead Temperature:	Soldering, (10 sec.)	+260°C		
	Vapor Phase (60 sec.)	+215°C		
	Infrared (15 sec.)	+220°C		

- (1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- Without PCB copper enhancements. The maximum power dissipation must be de-rated at elevated temperatures and is limited by T_{JMAX} (maximum junction temperature), θ_{J-A} (junction to ambient thermal resistance) and T_A (ambient temperature). The maximum power dissipation at any temperature is: PDiss_{MAX} = $(T_{JMAX} - T_A)/\theta_{J-A}$ up to the value listed in the Absolute Maximum Ratings. The human body model is a 100 pF capacitor discharged through a 1.5 k Ω resistor into each pin. The machine model is a 200 pF
- capacitor discharged directly into each pin.

Operating Range⁽¹⁾

Storage Temperature Range	−65°C to +150°C
Ambient Temperature Range	−40°C to +85°C
Junction Temperature Range	-40°C to +125°C

(1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.



Electrical Characteristics — LM4125-2.048V and 2.5V

Unless otherwise specified $V_{IN}=3.3V$, $I_{LOAD}=0$, $C_{OUT}=0.01\mu F$, $T_A=T_j=25^{\circ}C$. Limits with standard typeface are for $T_j=25^{\circ}C$, and limits in **boldface type** apply over the $-40^{\circ}C \le T_A \le +85^{\circ}C$ temperature range.

Symbol	Parameter	Conditions	Min (1)	Тур (2)	Max (1)	Units		
V_{OUT}	Output Voltage Initial Accuracy LM4125A-2.048 LM4125A-2.500				±0.2	%		
	LM4125-2.048 LM4125-2.500				±0.5	%		
TCV _{OUT} /°C	Temperature Coefficient	-40 °C $\leq T_A \leq +125$ °C		14	50	ppm/°c		
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	$3.3V \le V_{IN} \le 6V$		0.0007	0.008 0.01	%/V		
		0 mA ≤ I _{LOAD} ≤ 1 mA		0.03	0.08 0.17			
$\Delta V_{OUT}/\Delta I_{LOAD}$	Load Regulation	1 mA ≤ I _{LOAD} ≤ 5 mA		0.01	0.04 0.1	%/mA		
		-1 mA ≤ I _{LOAD} ≤ 0 mA		0.04	0.12			
		-5 mA ≤ I _{LOAD} ≤ -1 mA		0.01				
		$I_{LOAD} = 0 \text{ mA}$		45	65 100			
V_{IN} - V_{OUT}	Dropout Voltage ⁽³⁾	$I_{LOAD} = +1 \text{ mA}$		120	150 200	mV		
		$I_{LOAD} = +5 \text{ mA}$		180	210 300	-		
V _N	Output Noise Voltage (4)	0.1 Hz to 10 Hz		20		μV_{PP}		
		10 Hz to 10 kHz		36		μV_{PP}		
Is	Supply Current			160	257 290	μΑ		
		$V_{IN} = 3.3V, V_{OUT} = 0$		15				
1	Short Circuit Current		6		30	mA		
I _{SC}	Short Circuit Current	$V_{IN} = 6V$, $V_{OUT} = 0$		17		III/A		
			6		30			
Hyst	Thermal Hysteresis (5)	-40°C ≤ T _A ≤ 125°C		0.5		mV/V		
ΔV_{OUT}	Long Term Stability ⁽⁶⁾	1000 hrs. @ 25°C		100		ppm		

⁽¹⁾ Limits are 100% production tested at 25°C. Limits over the operating temperature range are ensured through correlation using Statistical Quality Control (SQC) methods. The limits are used to calculate Outgoing Quality Level (AOQL).

Product Folder Links: LM4125

Typical numbers are at 25°C and represent the most likely parametric norm.

Dropout voltage is the differential voltage between V_{OUT} and V_{IN} at which V_{OUT} changes \leq 1% from V_{OUT} at $V_{IN} = 3.3V$ for 2.0V, 2.5V and 5V for 4.1V. A parasitic diode exists between input and output pins; it will conduct if V_{OUT} is pulled to a higher voltage than V_{IN} . Output noise voltage is proportional to V_{OUT} . V_N for other voltage option is calculated using $(V_{N(1.8V)}/1.8) * V_{OUT}$. V_N (2.5V) =

 $^{(36\}mu V_{PP}/1.8) * 2.5 = 46\mu V_{PP}$

Thermal hysteresis is defined as the change in +25°C output voltage before and after exposing the device to temperature extremes.

Long term stability is change in V_{REF} at 25°C measured continuously during 1000 hrs.



Electrical Characteristics — LM4125-4.096V

Unless otherwise specified $V_{IN}=5V$, $I_{LOAD}=0$, $C_{OUT}=0.01\mu F$, $T_A=T_j=25^{\circ}C$. Limits with standard typeface are for $T_j=25^{\circ}C$, and limits in **boldface type** apply over the $-40^{\circ}C \le T_A \le +85^{\circ}C$ temperature range.

Symbol	Parameter	Conditions	Min (1)	Typ (2)	Max (1)	Units	
V _{OUT}	Output Voltage Initial Accuracy LM4125A-4.096				±0.2	%	
	LM4125-4.096				±0.5	%	
TCV _{OUT} /°C	Temperature Coefficient	-40°C ≤ T _A ≤ +125°C		14	50	ppm/°c	
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	5V ≤ V _{IN} ≤ 6V		0.0007	0.008 0.01	%/V	
ΔV _{OUT} /ΔΙ _{LOAD}		0 mA ≤ I _{LOAD} ≤ 1 mA		0.03	0.08 0.17		
	Load Regulation	1 mA ≤ I _{LOAD} ≤ 5 mA		0.01	0.04 0.1	%/mA	
		-1 mA ≤ I _{LOAD} ≤ 0 mA		0.04	0.12		
		-5 mA ≤ I _{LOAD} ≤ -1 mA		0.01			
V _{IN} -V _{OUT}	Dropout Voltage (3)	I _{LOAD} = 0 mA		45	65 100		
		I _{LOAD} = +1 mA		120	150 200	mV	
		$I_{LOAD} = +5 \text{ mA}$		180	210 300		
V _N	Output Noise Voltage (4)	0.1 Hz to 10 Hz		20		μV_{PP}	
		10 Hz to 10 kHz		36		μV_{PP}	
I _S	Supply Current			160	257 290	μA	
		V _{OUT} = 0		15			
I _{sc}	Chart Circuit Current		6		30	A	
	Short Circuit Current	$V_{IN} = 6V$, $V_{OUT} = 0$		17		mA	
			6		30		
Hyst	Thermal Hysteresis (5)	-40°C ≤ T _A ≤ 125°C		0.5		mV/V	
ΔV_{OUT}	Long Term Stability (6)	1000 hrs. @ 25°C		100		ppm	

⁽¹⁾ Limits are 100% production tested at 25°C. Limits over the operating temperature range are ensured through correlation using Statistical Quality Control (SQC) methods. The limits are used to calculate Outgoing Quality Level (AOQL).

⁽²⁾ Typical numbers are at 25°C and represent the most likely parametric norm.

⁽³⁾ Dropout voltage is the differential voltage between V_{OUT} and V_{IN} at which V_{OUT} changes ≤ 1% from V_{OUT} at V_{IN} = 3.3V for 2.0V, 2.5V and 5V for 4.1V. A parasitic diode exists between input and output pins; it will conduct if V_{OUT} is pulled to a higher voltage than V_{IN}.

⁽⁴⁾ Output noise voltage is proportional to V_{OUT} . V_N for other voltage option is calculated using $(V_{N(1.8V)}/1.8) * V_{OUT}$. V_N (2.5V) = $(36\mu V_{PP}/1.8) * 2.5 = 46\mu V_{PP}$.

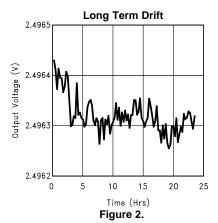
⁽⁵⁾ Thermal hysteresis is defined as the change in +25°C output voltage before and after exposing the device to temperature extremes.

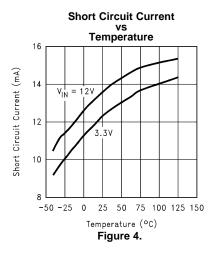
⁽⁶⁾ Long term stability is change in V_{REF} at 25°C measured continuously during 1000 hrs.

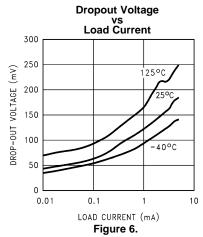


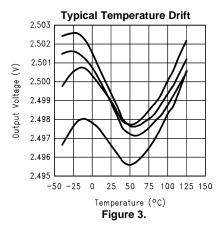
LM4125 Typical Operating Characteristics

Unless otherwise specified, V_{IN} = 3.3V, V_{OUT} = 2.5V, I_{LOAD} = 0, C_{OUT} = 0.022 μF and T_A = 25°C.









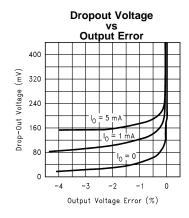
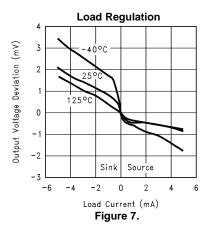


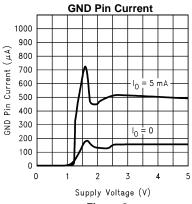
Figure 5.



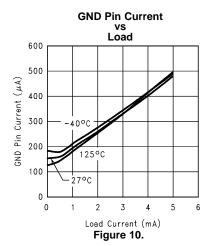


LM4125 Typical Operating Characteristics (continued)

Unless otherwise specified, $V_{IN}=3.3V$, $V_{OUT}=2.5V$, $I_{LOAD}=0$, $C_{OUT}=0.022\mu F$ and $T_A=25^{\circ}C$.







Output Impedance vs Frequency

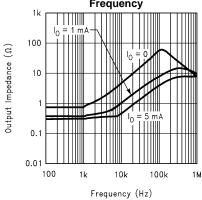


Figure 12.

GND Pin Current at No Load

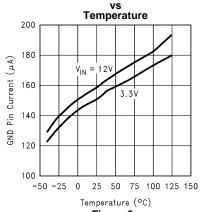


Figure 9.

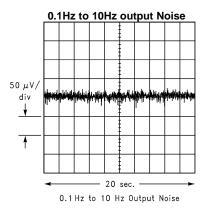


Figure 11.

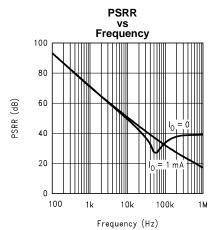


Figure 13.



LM4125 Typical Operating Characteristics (continued)

Unless otherwise specified, V_{IN} = 3.3V, V_{OUT} = 2.5V, I_{LOAD} = 0, C_{OUT} = 0.022 μ F and T_A = 25°C.

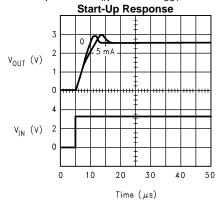
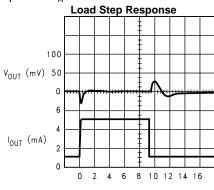


Figure 14.



Time (μs) Figure 15.

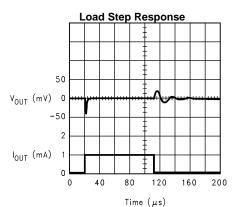


Figure 16.

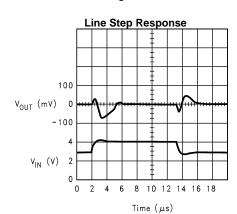
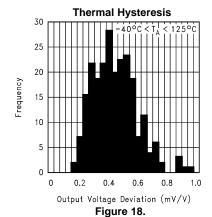


Figure 17.



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PIN FUNCTIONS

Output (Pin 5): Reference Output. Input (Pin 4): Positive Supply.

Ground (Pin 2): Negative Supply or Ground Connection.

APPLICATION HINTS

The standard application circuit for the LM4125 is shown in Figure 19. It is designed to be stable with ceramic output capacitors in the range of $0.022\mu F$ to $0.1\mu F$. Note that $0.022\mu F$ is the minimum required output capacitor. These capacitors typically have an ESR of about 0.1 to 0.5Ω . Smaller ESR can be tolerated, however larger ESR can not. The output capacitor can be increased to improve load transient response, up to about $1\mu F$. However, values above $0.047\mu F$ must be tantalum. With tantalum capacitors, in the $1\mu F$ range, a small capacitor between the output and the reference pin is required. This capacitor will typically be in the 50pF range. Care must be taken when using output capacitors of $1\mu F$ or larger. These application must be thoroughly tested over temperature, line and load.

An input capacitor is typically not required. However, a $0.1\mu F$ ceramic can be used to help prevent line transients from entering the LM4125. Larger input capacitors should be tantalum or aluminum.

The typical thermal hysteresis specification is defined as the change in $+25^{\circ}$ C voltage measured after thermal cycling. The device is thermal cycled to temperature -40° C and then measured at 25° C. Next the device is thermal cycled to temperature $+125^{\circ}$ C and again measured at 25° C. The resulting V_{OUT} delta shift between the 25° C measurements is thermal hysteresis. Thermal hysteresis is common in precision references and is induced by thermal-mechanical package stress. Changes in environmental storage temperature, operating temperature and board mounting temperature are all factors that can contribute to thermal hysteresis.

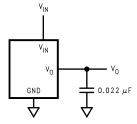


Figure 19. Standard Application Circuit

INPUT CAPACITOR

Noise on the power-supply input can effect the output noise, but can be reduced by using an optional bypass capacitor between the input pin and the ground.

PRINTED CIRCUIT BOARD LAYOUT CONSIDERATION

The mechanical stress due to PC board mounting can cause the output voltage to shift from its initial value. References in SOT packages are generally less prone to assembly stress than devices in Small Outline (SOIC) package.

To reduce the stress-related output voltage shifts, mount the reference on the low flex areas of the PC board such as near to the edge or the corner of the PC board.

Submit Documentation Feedback

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Typical Application Circuits

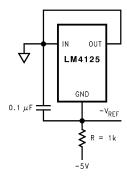


Figure 20. Voltage Reference with Negative Output

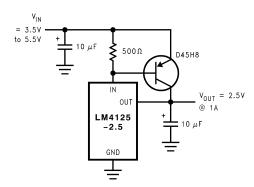
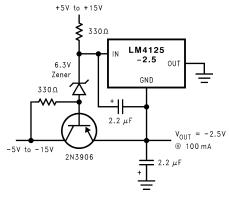


Figure 21. Precision High Current Low Dropout Regulator



V_{REF}

IN OUT

LM4125

GND

R/2

R/2

Figure 22. Precision High Current Negative Voltage Regulator

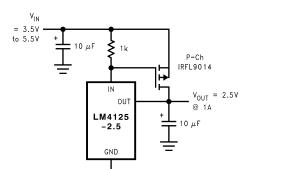


Figure 24. Precision High Current Low Droput Regulator

Figure 23. Voltage Reference with Complimentary Output

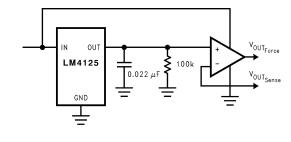


Figure 25. Precision Voltage Reference with Force and Sense Output



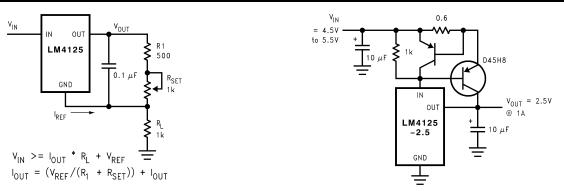


Figure 26. Programmable Current Source

Figure 27. Precision Regulator with Current Limiting Circuit

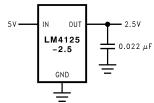


Figure 28. Power Supply Splitter





REVISION HISTORY

Cł	hanges from Original (April 2013) to Revision A	Pa	ge
•	Changed layout of National Data Sheet to TI format		10



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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing		Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
LM4125IM5-2.5/NOPB	LIFEBUY	SOT-23	DBV	5	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	R81B	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM4125IM5-2.5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

	Device	Package Type	pe Package Drawing		SPQ	Length (mm)	Width (mm)	Height (mm)	
I	LM4125IM5-2.5/NOPB	SOT-23	DBV	5	1000	208.0	191.0	35.0	



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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